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**FORM PTO-1449**

Atty. Docket No.:  
H0004823  
(1139.1140101)

Serial No.:  
10/606,104

Applicant: Txu-Yu Wang et al.

Filing Date:  
June 25, 2003

Group Art: 2828  
unknown

LIST OF PATENTS AND PUBLICATIONS FOR  
APPLICANT'S INFORMATION  
DISCLOSURE STATEMENT

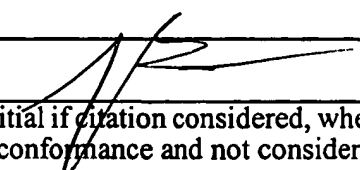
U.S. PATENT DOCUMENTS

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	5,864,575	01/1999	Ohiso et al.			
	5,978,398	11/1999	Ramdani et al.			
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	6,553,051	04/2003	Tan et al.			

FOREIGN PATENT DOCUMENTS

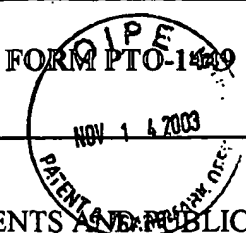
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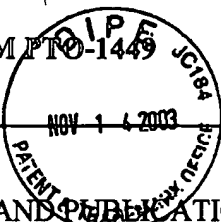
DATE CONSIDERED: 12/11/04

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Page 1 of 13 <div data-bbox="349 94 592 325" style="text-align: center;">  </div>	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
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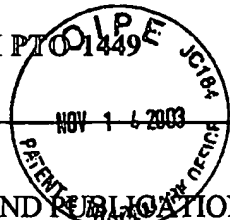
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PN	US2001/0004414 A1	06/21/2001	Kuhn et al.			
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PN	5,216,263	06/01/1993	Paoli			
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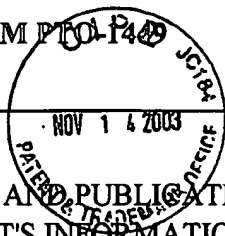
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PW	5,396,508	03/17/1995	Bour et al.			
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	5,412,678	05/02/1995	Treat et al.			
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	5,590,145	12/31/1996	Nitta			
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	5,642,376	06/24/1997	Olbright et al.			
	5,645,462	07/08/1997	Banno et al.			
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	5,679,963	10/21/1997	Klem et al.			
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	5,696,023	12/09/1997	Holonyak, Jr., et al.			
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	5,727,013	03/10/1988	Botez et al.			
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10/606,104

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June 25, 2003

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pn	5,892,784	04/06/1999	Tan et al.			
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	5,896,408	04/20/1999	Corzine et al.			
	5,901,166	05/04/1999	Nitta et al.			
	5,903,588	05/1999	Guenter et al.			
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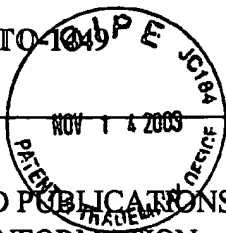
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	6,154,480	11/28/2000	Magnusson et al.			
	6,185,241	02/06/2001	Sun			
	6,191,890	02/20/2001	Baets et al			
	6,208,681 B1	03/27/2001	Thorton			
	6,212,312	04/03/2001	Grann et al			
	6,238,944 B1	05/29/2001	Floyd			
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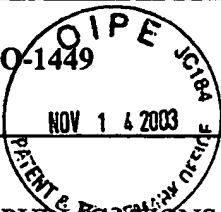
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	6,490,311	12/03/2002	Boucart et al.			
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	6,536,959	03/25/2003	Kuhn et al.			
	6,542,531	04/01/2003	Sirbu et al.			
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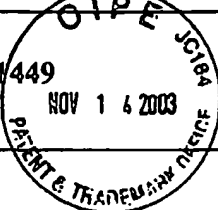
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	JP 5299779 /	11/12/1993	JP	Abstract
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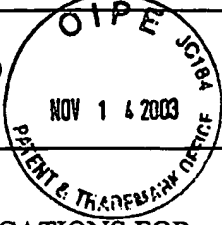


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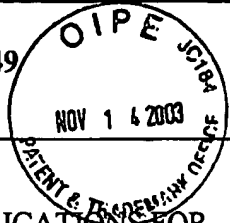
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/	<input checked="" type="checkbox"/> Choquette, et al., "VCSELs in information systems: 10Gbps <sup>-1</sup> oxide VCSELs for data communication", <u>Optics In Information Systems</u> , Vol. 12, No. 1, page 5, SPIE International Technical Group Newsletter, April 2001.
/	<input checked="" type="checkbox"/> Chua, et al., "Low-Threshold 1.57- $\mu$ m VC-SEL's Using Strain-Compensated Quantum Wells and Oxide/Metal Backmirror," <u>IEEE Photonics Technology Letters</u> , Vol 7, No. 5, pp. 444-446, May 1995.
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<p>pu</p>	G. G. Ortiz, et al., "Monolithic Integration of In <sub>0.2</sub> Ga <sub>0.8</sub> As Vertical Cavity Surface-Emitting Lasers with Resonance-Enhanced Quantum Well Photodetectors", <u>Electronics Letters</u> , Vol. 32, No. 13, June 20, 1996, pp. 1205-1207.
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<p>✓</p>	Jiang et al., "High-Frequency Polarization Self-Modulation in Vertical-Cavity Surface-Emitting Lasers", <u>Appl. Phys. Letters</u> , Vol. 63, No. 26, December 27, 1993, pp. 2545-2547.

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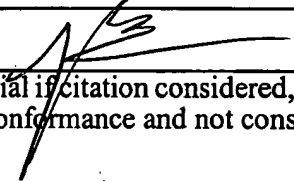
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EXAMINER: 	DATE CONSIDERED: 12/11/04
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.